

WLAN8101H 2.4 GHz Wi-Fi 6 Front-End Module Rev. 6 — 11 August 2020

Product data sheet

General description 1

The WLAN8101H is a 2.4 GHz 2 x 2 MIMO RFFE for Wi-Fi 6 applications in a 3 mm x 4 mm package.

The WLAN8101H includes two monolithic front-end ICs. Each front-end IC includes a transmit amplifier with directional coupler, a low-noise receive amplifier and a transmit/ receive switch with a Bluetooth channel. The power amplifier supports 3 different TX gain modes to improve power efficiency. The directional coupler improves transmit-power sensing accuracy.

WLAN8101H also includes coexistence filters for both transmit and receive channels.

The device is matched to 50 Ω and integrates harmonic and out of band filtering which minimizes the layout area in the application.

Features and benefits 2

- Small-size 2 x 2 MIMO RFFE for Wi-Fi 6 applications
- Integrated power amplifiers with multiple operation modes for dynamic power efficiency and linearity control
- Full ISM band 2.402 GHz to 2.482 GHz
- 3 TX operation modes enabling flexibility for power efficiency adaptation
- Integrated low-noise amplifiers supporting high gain and bypass modes
- Integrated SPDT switches for single antenna RX and TX operation
- Integrated directional couplers for precise transmit power control
- Requires no external matching components, DC free RF ports, except for the ANT, and BT ports (on-chip ESD coil)
- Integrated RF decoupling capacitors for all V_{CC} and control pins
- · Low profile, small-size 3 mm x 4 mm package
- Integrated ESD protection on all pins
 - Human Body Model (HBM) according to ANSI/ESDA/JEDEC standard JS-001 exceeds 2 kV

 Charged Device Model (CDM) according to ANSI/ESDA/JEDEC standard JS-002 exceeds 500 V except for ANT pins the value is 400 V

3 **Applications**

- Wi-Fi 6 support
- · Smartphones, tablets, netbooks, and other portable computing devices
- · Module applications for embedded systems



4 Quick reference data

Table 1. Quick reference data

 T_{amb} = 25 °C; V_{CC} = 3.85 V; V_{IH} = 1.8 V; V_{IL} = 0 V; Z_s = Z_L = 50 Ω ; P_i = - 30 dBm for RX, P_i = -10 dBm for TX, and BT, f = 2.402 GHz to 2.482 GHz, single channel performance. Unless otherwise specified. All values are measured at product input/output as reference plane. Measurements are done using the application schematic. (See application note AN12719)

| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|---------------------|--|--|-----|---------|-----|------|
| RF perfor | mance from ANT to RX | | | | | 1 |
| I _{CC} | supply current | RX_gain | - | 10.5 | - | mA |
| | | RX_bypass ^[1] | - | 24 | - | μA |
| G _p | power gain | RX_gain | - | 16.5 | - | dB |
| | | RX_bypass | - | -5.5 | - | dB |
| NF | noise figure | RX_gain | - | 2 | - | dB |
| P _{i(1dB)} | input power at 1 dB gain compression point | RX_gain | - | -6.5 | - | dBm |
| RLi | input return loss | RX_gain mode, P _i = -20 dBm, looking into ANT pin | - | 10.5 | - | dB |
| | | RX_bypass mode, looking into ANT pin | - | 13.5 | - | dB |
| RLo | output return loss | RX_gain mode, P _i = -20 dBm, looking into RX pin | - | 12 | - | dB |
| | RX_bypass mode, looking into RX pin | | - | 14 | - | dB |
| RF perfor | mance from TX to ANT | · | | | | |
| I _{CC} | supply current | TX_gain1, $P_o = 20.5 \text{ dBm}$ | - | 285 | - | mA |
| G _p | power gain | TX_gain1 | - | 32.5 | - | dB |
| | | TX_gain2 | - | 30 | - | dB |
| | | TX_gain3 | - | 18 | - | dB |
| G _{flat} | gain flatness | all TX_gain modes, 40 MHz bandwidth | - | +/-0.25 | - | dB |
| | | all TX_gain modes, for entire frequency range | - | +/-0.75 | - | dB |
| EVM _{dyn} | dynamic error vector magnitude | 11ax MCS10/11, HE40, TX_gain1, P _o = 14.5 dBm, 180 µs burst, 50 % duty cycle | - | -45 | - | dB |
| RLi | input return loss | TX_gain1, and TX_gain2 looking into TX pin | - | 12 | - | dB |
| | | TX_gain3, looking into TX pin | - | 10 | - | dB |
| RLo | output return loss | all TX_gain modes, looking into ANT pin | - | 12 | - | dB |
| RF perfor | mance from BT to ANT | · | | | | |
| I _{CC} | supply current | BT_gain, NO RF | - | 70 | - | mA |
| | | BT_bypass | - | 24 | - | μA |
| G _p | power gain | BT_gain | - | 23 | - | dB |
| | | BT_bypass | - | -2.1 | - | dB |
| RLi | input return loss | BT_gain, looking into BT pin | - | 7 | - | dB |
| | | BT_bypass mode, looking into BT pin | - | 15 | - | dB |
| RLo | output return loss | BT_gain, looking into ANT pin | - | 12 | - | dB |
| | | BT_bypass, looking into ANT pin | - | 15 | - | dB |

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Table 1. Quick reference data...continued

 T_{amb} = 25 °C; V_{CC} = 3.85 V; V_{IH} = 1.8 V; V_{IL} = 0 V; Z_s = Z_L = 50 Ω ; P_i = - 30 dBm for RX, P_i = -10 dBm for TX, and BT, f = 2.402 GHz to 2.482 GHz, single channel performance. Unless otherwise specified. All values are measured at product input/output as reference plane. Measurements are done using the application schematic. (See application note AN12719)

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------------|--|---|-----|-----|-----|------|
| EVM _{dif(peak)} | peak differential error vector magnitude | $BT_gain, 8DPSK, P_o = 19 dBm -$ | | 2.5 | - | % |
| EVM _{diff(RMS)} | RMS differential error vector magnitude | BT_gain, 8DPSK, P _o = 19 dBm | - | 1 | - | % |
| ISL _r | reverse isolation | BT_gain | - | 32 | - | dB |

[1] total leakage of both channels

5 Ordering information

Table 2. Ordering information

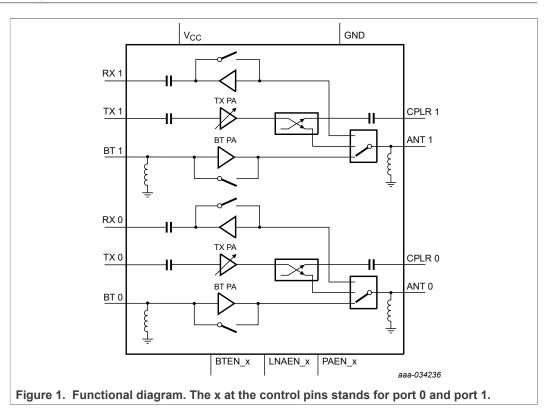
| | Orderable part number | Package | Package | | | | | | |
|-----------|--------------------------|-----------|---|-----------|--|--|--|--|--|
| number | | Name | Description | Version | | | | | |
| WLAN8101H | WLAN8101H MP | HFCPLGA38 | 3 mm x 4 mm x 0.65 mm package, 0.35 mm pitch, 38 pins | SOT2022-1 | | | | | |

6 Marking

| Table 3. Marking | |
|------------------|--------------|
| Type number | Marking code |
| WLAN8101H | 8101H |

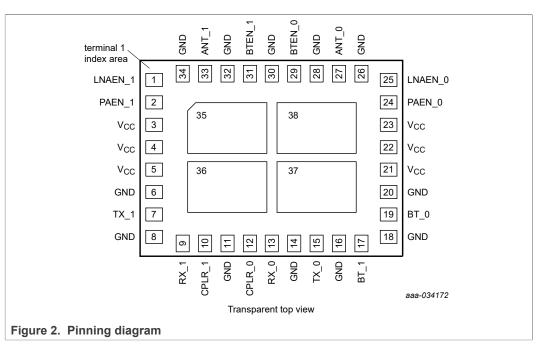
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7 Functional diagram



8 Pinning information

8.1 Pinning diagram



8.2 Pin description

| Pin | Symbol | Description |
|--|-----------------|----------------|
| 6, 8, 11, 14, 16, 18, 20, 26, 28, 30, 32, 34, 35, 36, 37, and 38 | GND | Ground |
| 1 | LNAEN_1 | LNA enable |
| 2 | PAEN_1 | PA enable |
| 3, 4, 5, 21, 22, and 23 | V _{CC} | supply voltage |
| 7 | TX_1 | TX port |
| 9 | RX_1 | RX port |
| 10 | CPLR_1 | coupler port |
| 12 | CPLR_0 | coupler port |
| 13 | RX_0 | RX port |
| 15 | TX_0 | TX port |
| 17 | BT_1 | Bluetooth port |
| 19 | BT_0 | Bluetooth port |
| 24 | PAEN_0 | PA enable |
| 25 | LNAEN_0 | LNA enable |
| 27 | ANT_0 | antenna port |

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| Table 4. Pin descriptioncontinued |
|-----------------------------------|
|-----------------------------------|

| Pin | Symbol | Description |
|-----|--------|-------------------|
| 29 | BTEN_0 | Blue Tooth enable |
| 31 | BTEN_1 | Blue Tooth enable |
| 33 | ANT_1 | antenna port |

9 Functional description

9.1 Parallel interface control states per MIMO channel

Table 5. Parallel interface control states per MIMO channel

Control pins , BTEN_x, LNAEN_x, and PAEN_x, contain internal pull-down resistors. The parallel interface table applies to both _0 and _1 control pins.^[1]

| BTEN_x | LNAEN_x | PAEN_x | Signal routing | Operating mode | Mode description | LNA | PA |
|--------|---------|--------|----------------|----------------|---------------------------|-----|-----|
| 0 | 0 | 1 | TX to ANT | TX_gain1 | high gain, high linearity | off | on |
| 1 | 0 | 1 | TX to ANT | TX_gain2 | 3 dB back off | off | on |
| 1 | 1 | 1 | TX to ANT | TX_gain3 | low gain mode | off | on |
| 0 | 1 | 0 | ANT to RX | RX_gain | | on | off |
| 0 | 0 | 0 | ANT to RX | RX_bypass | | off | off |
| 1 | 0 | 0 | BT to ANT | BT_bypass | | off | off |
| 1 | 1 | 0 | BT to ANT | BT_gain | | off | on |
| 0 | 1 | 1 | n.a. | reserved | | - | - |
| x | x | x | n.a. | reserved | | - | - |

[1] Binary represented logic levels, where 0 denotes a logic low ($V_i \le V_{IL}$) and 1 denotes a logic high ($V_i \ge V_{IH}$)

10 Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|------------------|--|---|----------|--------|---------|------|
| V _{cc} | supply voltage | | -0.3 | - | 6 | V |
| Vi | input voltage | on pin BTEN_x, LNAEN_x, and PAEN_x | -0.3 | - | 3.6 | V |
| Pi | input power | on ANT_x pin, RX_gain, MCS0 | - | - | 10 | dBm |
| | | on ANT_x pin, RX_bypass, MCS0 | - | - | 15 | dBm |
| | | TX_x pin, TX_gain1, MCS0 | - | - | 10 | dBm |
| | | BT_x pin, BT_gain mode GFSK | - | - | 10 | dBm |
| | | BT_x pin, BT_bypass mode GFSK | - | - | 28 | dBm |
| TX_RUG | TX ruggedness (no irreversible damage) | V_{CC} = 4.75 V, applied to TX_gain1 mode, P _o = 26.5 dBm_MCS0, at 50 Ω , the required P _i level is kept constant during ruggedness test, VSWR all phases | - | 10:1 | - | - |
| BT_RUG | BT ruggedness (no irreversible damage) | V_{CC} = 4.75 V, applied in BT_gain mode. P_o = 25 dBm_GFSK at 50 Ω , the required P_i level is kept constant during ruggedness test, VSWR all phases | - | 10:1 | - | - |
| T _{stg} | storage temperature | | -55 | - | 125 | °C |
| Tj | junction temperature | | - | - | 175 | °C |
| T _{mb} | mounting base temperature | - | - | - | 100 | °C |
| V _{ESD} | Electrostatic Discharge Voltage | Human Body Model (HBM) according to ANSI/ESDA/JEDEC standard JS-001 | - | 2 | - | kV |
| | | Charged Device Model (CDM) according to ANSI/ES | DA/JEDEC | standa | rd JS-0 | 02 |
| | | pins ANT_0, and ANT_1 | - | 400 | - | V |
| | | all other pins | - | 500 | - | V |

11 Recommended operating conditions

Table 7. Recommended operating conditions

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-------------------|--------------------------|------------------------|---------|-------|------|-------|------|
| f _{oper} | operating frequency | | | 2.402 | - | 2.482 | GHz |
| V _{CC} | supply voltage | on pin V _{CC} | [1] [2] | 2.7 | 3.85 | 4.75 | V |
| V _{IH} | HIGH-level input voltage | | | 1.6 | - | 3.6 | V |
| V _{IL} | LOW-level input voltage | | | 0 | | 0.4 | V |
| T _{amb} | ambient temperature | | | -40 | 25 | 85 | °C |

[1]

Product is functional with reduced performance at supply voltages from 2.5 V to 2.7 V. Product withstands 30000 charger insert and pull-out events with a duration of 100 ms and a maximum supply voltage of 5.25 V. [2]

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12 Thermal characteristics

Table 8. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|--|------------|-----|-----|-----|------|
| R _{th(j-mb)} | junction to mounting base thermal resistance | | - | 25 | - | K/W |

13 Characteristics

13.1 Switching time performance

 T_{amb} = 25 °C; V_{CC1} = V_{CC2} = V_{CC3} = 3.85 V; All ports are terminated with 50 Ω .

| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|-----------------------|-------------------|---|----------|---------|-------|------|
| t _{on(LNA)} | LNA turn-on time | from 10 % of control signal to 90 % LNA output level, RX_bypass to LNA transition | - | 150 | - | ns |
| t _{off(LNA)} | LNA turn-off time | from 90 % of control signal to 10 % LNA output level, LNA to RX_bypass transition | - | 100 | - | ns |
| t _{on(TX)} | TX turn-on time | from 10 % of control signal to 94 % TX output level, RX_bypas | ss to T> | (trans | ition | |
| | | TX_gain1, and TX_gain2 | - | 350 | - | ns |
| | | TX_gain3 | - | 630 | - | ns |
| $t_{\text{off}(TX)}$ | TX turn-off time | from 90 % of control signal to 10 % TX output level, TX to RX_bypass transition | - | 400 | - | ns |
| t _{on(BT)} | BT turn-on time | from 10 % of control signal to 90 % of BT output level, RX_bypass to BT_gain transition | - | 350 | - | ns |
| t _{off(BT)} | BT turn-off time | from 90 % of control signal to 10 % of BT output level, BT_gain to RX_bypass transition | - | 400 | - | ns |

13.2 RF Performance from ANT to RX

Table 10. RF Performance from ANT to RX

 $T_{amb} = 25 \text{ °C}$; $V_{CC} = 3.85 \text{ V}$; $V_{IH} = 1.8 \text{ V}$; $V_{IL} = 0 \text{ V}$; $Z_s = Z_L = 50 \Omega$; $P_i = -30 \text{ dBm}$ for RX, f = 2.402 GHz to 2.482 GHz, single channel performance. Unless otherwise specified. All values are measured at product input/output as reference plane. Measurements are done using the application schematic. (See application note AN12719)

| Symbol | nbol Parameter Conditions | | Min | Тур | Мах | Unit |
|-------------------|---------------------------|---|-----|---------|-----|------|
| I _{CC} | supply current | RX_gain | - | 10.5 | - | mA |
| | | RX_bypass ^{[1} |] - | 24 | - | μA |
| G _p | power gain | RX_gain | - | 16.5 | - | dB |
| | | RX_bypass | - | -5.5 | - | dB |
| G _{flat} | power gain flatness | RX_gain, peak-to-peak over any 40 MHz band | - | +/-0.25 | - | dB |
| | | RX_gain, over full RF bandwidth | - | +/-0.75 | - | dB |
| | | RX_bypass, peak-to-peak over any 40 MHz band | - | +/-0.25 | - | dB |
| | | RX_bypass, over full RF bandwidth | - | +/-0.75 | - | dB |
| NF | noise figure | RX_gain | - | 2 | - | dB |
| RLi | input return loss | RX_gain, P _i = -20 dBm, looking into ANT pin | - | 10.5 | - | dB |
| | | RX_bypass, looking into ANT pin | - | 13.5 | - | dB |
| RLo | output return loss | RX_gain, P _i = -20 dBm, looking into RX pin | - | 12 | - | dB |
| | | RX_bypass, looking into RX pin | - | 14 | - | dB |

Table 9. Switching time performance

Table 10. RF Performance from ANT to RX...continued

 T_{amb} = 25 °C; V_{CC} = 3.85 V; V_{IH} = 1.8 V; V_{IL} = 0 V; Z_s = Z_L = 50 Ω ; P_i = - 30 dBm for RX, f = 2.402 GHz to 2.482 GHz, single channel performance. Unless otherwise specified. All values are measured at product input/output as reference plane. Measurements are done using the application schematic. (See application note AN12719)

| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|--|--|--------------------------|-----|------|-----|------|
| IP3 _i input third orde intercept point | input third order | RX_gain ^[2] | - | 4.5 | - | dBm |
| | intercept point | RX_bypass ^[3] | - | 35 | - | dBm |
| i(idb) | input power at 1 dB gain compression point | RX_gain | - | -6.5 | - | dBm |
| | | RX_bypass | - | 18 | - | dBm |

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13.3 RF Performance from TX to ANT

Table 11. RF Performance from TX to ANT

 T_{amb} = 25 °C; V_{CC} = 3.85 V; V_{IH} = 1.8 V; V_{IL} = 0 V; Z_s = Z_L = 50 Ω ; P_i = -10 dBm for TX, f = 2.402 GHz to 2.482 GHz, single channel performance. Unless otherwise specified. All values are measured with product input/output as reference plane. Measurements are done using the application schematic. (See application note AN12719)

| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit | |
|-----------------------|---------------------------|--|-----|---------|-----|------|--|
| I _{CC} | supply current | TX_gain1, no RF | - | 195 | - | mA | |
| | | TX_gain2, no RF | - | 140 | - | mA | |
| | | TX_gain3, no RF | - | 60 | - | mA | |
| | | TX_gain1, P _o = 16.5 dBm HE40 | - | 230 | - | mA | |
| | | TX_gain1, P _o = 19 dBm HT20 | - | 260 | - | mA | |
| | | TX_gain1, $P_o = 20.5 \text{ dBm HT40}$ | - | 285 | - | mA | |
| | | TX_gain1, P _o = 22.5 dBm 11g, 6 Mb/s | - | 335 | - | mA | |
| | | TX_gain1, $P_o = 24.5 \text{ dBm CCK}$ | - | 405 | - | mA | |
| | | TX_gain2, P _o = 16 dBm HT20 | - | 180 | - | mA | |
| | | TX_gain2, $P_o = 17.5 \text{ dBm HT40}$ | - | 195 | - | mA | |
| | | TX_gain2, P _o = 19.5 dBm 11g, 6 Mb/s | - | 220 | - | mA | |
| | | TX_gain3, $P_o = 9 \text{ dBm HT40}$ | - | 65 | - | mA | |
| G _p | power gain | TX_gain1 | - | 32.5 | - | dB | |
| | | TX_gain2 | - | 30 | - | dB | |
| | | TX_gain3 | - | 18 | - | dB | |
| G _{flat} g | gain flatness | all TX_gain modes, 40 MHz bandwidth | - | +/-0.25 | - | dB | |
| | | all TX_gain modes, for entire frequency range | - | +/-0.75 | - | dB | |
| RLi | input return | TX_gain1, and TX_gain2 looking into TX pin | - | 12 | - | dB | |
| | loss | TX_gain3, looking into TX pin | - | 10 | - | dB | |
| RLo | output return loss | TX_gain1, looking into ANT pin | - | 12 | - | dB | |
| | | TX_gain2, looking into ANT pin | - | 12 | - | dB | |
| | | TX_gain3, looking into ANT pin | - | 12 | - | dB | |
| SEM _{margin} | margin to | 11n, MCS0, 20 MHz, 180 µs burst, 50 % duty cycle | 1 | | 1 | | |
| | spectrum emission mask | TX_gain1, P _o = 21 dBm, ± 11 MHz | - | 10 | - | dB | |
| | | TX_gain1, P _o = 21 dBm, ± 20 MHz | - | 9 | - | dB | |
| | | TX_gain1, P _o = 21 dBm, ± 30 MHz ^[1] | - | 3 | - | dB | |
| | | 11g_6M, 180 µs burst, 50 % duty cycle | | | | | |
| | | TX_gain1, P _o = 21.5 dBm, ± 11 MHz | - | 12 | - | dB | |
| | | TX_gain1, P _o = 21.5 dBm, ± 20 MHz | - | 9 | - | dB | |
| | | TX_gain1, P _o = 21.5 dBm, ± 30 MHz | - | 3 | - | dB | |
| | | 11b_CCK, 180 µs burst, 50 % duty cycle | | 1 | | | |
| | | TX_gain1, P _o = 23 dBm, ± 11 MHz | - | 12 | - | dB | |
| | | TX_gain1, $P_o = 23 \text{ dBm}$, ± 22 MHz | - | 6 | - | dB | |

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Table 11. RF Performance from TX to ANT...continued

 T_{amb} = 25 °C; V_{CC} = 3.85 V; V_{IH} = 1.8 V; V_{IL} = 0 V; Z_s = Z_L = 50 Ω ; P_i = -10 dBm for TX, f = 2.402 GHz to 2.482 GHz, single channel performance. Unless otherwise specified. All values are measured with product input/output as reference plane. Measurements are done using the application schematic. (See application note AN12719)

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit | |
|--------------------|----------------------------|--|--------------|-------|-----|---------|--|
| EVM _{dyn} | dynamic | 11n, MCS0, 20 MHz, 180 µs burst, 50 % duty cycle | | | | | |
| | error vector magnitude | TX_gain1, P _o = 22 dBm | - | -26 | - | dB | |
| | | TX_gain2, P _o = 19 dBm | - | -33 | - | dB | |
| | | 11n, MCS7, HT20, 180 µs burst, 50 % duty cycle | | | | | |
| | | TX_gain1, P _o = 20.5 dBm | - | -31 | - | dB | |
| | | TX_gain2, P _o = 17.5 dBm | - | -37 | - | dB | |
| | | 11ax, MCS10, and MCS11, HE40, 180 µs burst, 50 | % duty cycle | | | | |
| | | TX_gain1, P _o = 16.5 dBm | - | -41.5 | - | dB | |
| | | TX_gain1, P _o = 14.5 dBm | - | -45 | - | dB | |
| | | TX_gain2, P _o = 13.5 dBm | - | -42.5 | - | dB | |
| | | TX_gain2, P _o = 11.5 dBm | - | -44.5 | - | dB | |
| | | TX_gain3, P _o = 4 dBm | - | -47 | - | dB | |
| a2H | second | TX_gain1, $P_o = 22.5 \text{ dBm}$, 11b_CCK | - | -21 | - | dBm/MHz | |
| | harmonic emission level | TX_gain2, P _o = 19.5 dBm, 11b_CCK | - | -23 | - | dBm/MHz | |
| a3H | third harmonic | TX_gain1, P _o = 22.5 dBm, 11b_CCK | - | -37 | - | dBm/MHz | |
| | emission level | TX_gain2, P _o = 19.5 dBm, 11b_CCK | - | -44 | - | dBm/MHz | |

[1] can be improved with optimized matching

13.4 RF Performance from BT to ANT

Table 12. RF Performance from BT to ANT

 $T_{amb} = 25 \text{ °C}$; $V_{CC} = 3.85 \text{ V}$; $V_{IH} = 1.8 \text{ V}$; $V_{IL} = 0 \text{ V}$; $Z_s = Z_L = 50 \Omega$; $P_i = -10 \text{ dBm}$ for BT, f = 2.402 GHz to 2.482 GHz, single channel performance. Unless otherwise specified. All values are measured at product input/output as reference plane. Measurements are done using the application schematic. (See application note AN12719)

| Symbol | Parameter | Conditions | | Min | Тур | Мах | Unit |
|-----------------|-------------------|---------------------------|-----|-----|------|--|------|
| I _{CC} | supply current | BT_gain | | | | - - - - - - (| |
| | supply current | No RF | | - | 70 | - | mA |
| | | P _o = 16.5 dBm | | - | 100 | - | mA |
| | | P _o = 18.5 dBm | | - | 115 | - | mA |
| | | P _o = 20.5 dBm | | - | 130 | - | mA |
| | | BT_bypass | [1] | - | 24 | - - - - - - | μA |
| G _p | power gain | BT_gain | | - | 23 | - | dB |
| | | BT_bypass | | - | -2.1 | - | dB |
| RLi | input return loss | BT_gain | | - | 7 | - | dB |
| | | BT_bypass | | - | 15 | - | dB |

Table 12. RF Performance from BT to ANT...continued

 $T_{amb} = 25 \text{ °C}$; $V_{CC} = 3.85 \text{ V}$; $V_{IH} = 1.8 \text{ V}$; $V_{IL} = 0 \text{ V}$; $Z_s = Z_L = 50 \Omega$; $P_i = -10 \text{ dBm}$ for BT, f = 2.402 GHz to 2.482 GHz, single channel performance. Unless otherwise specified. All values are measured at product input/output as reference plane. Measurements are done using the application schematic. (See application note AN12719)

| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|--------------------------|---|---|-----|-----|-----|------|
| RL_{o} | output return loss | all BT modes | - | 12 | - | dB |
| | | BT_bypass | - | 15 | - | dB |
| ACP | Adjacent channel | BT_gain, GFSK P _o = 22 dBm | | 1 | - | - |
| | power | at +/- 2 MHz offset | - | -46 | - | dBm |
| | | at +/- 3 MHz offset | - | -52 | - | dBm |
| e _{sp(ib)} | Inband spurious emission | BT_gain, 8DPSK, and Pi/4-DQPSK, P _o = 19 dBm | | | | |
| | | at +/- 2 MHz offset | - | -21 | - | dBm |
| | | at +/- 3 MHz offset | - | -40 | - | dBm |
| EVM _{dif(peak)} | peak differential error vector magnitude | BT_gain, 8DPSK P _o = 19 dBm | - | 2.5 | - | % |
| EVM _{diff(RMS} | RMS differential error vector magnitude | BT_gain, 8DPSK P _o = 19 dBm | - | 1 | - | % |
| ISLr | reverse isolation | BT_gain | - | 32 | - | dB |

[1] one channel in BT_bypass, one channel in RX_bypass

13.5 Directional Coupler

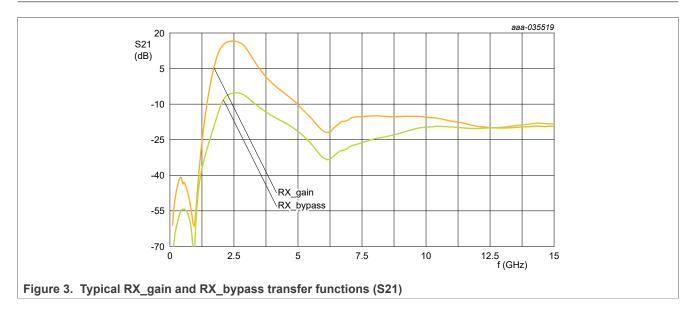
Table 13. Power coupler RF Performance

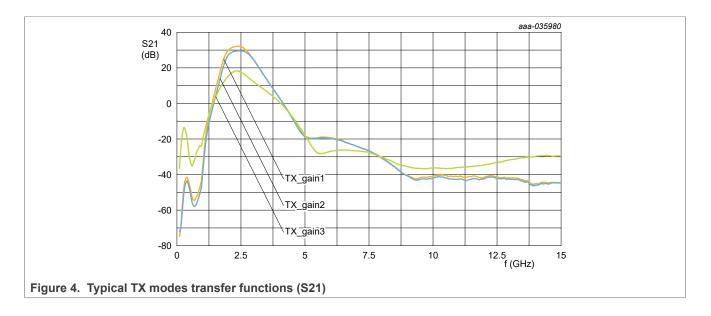
 T_{amb} = 25 °C; V_{CC} = 3.85 V; V_{IH} = 1.8 V; V_{IL} = 0 V; Z_s = Z_L = 50 Ω ; P_i = - 30 dBm for RX, P_i = -10 dBm for TX, f = 2.402 GHz to 2.482 GHz, single channel performance. Unless otherwise specified. All values are measured at product input/output as reference plane. Measurements are done using the application schematic. (See application note AN12719)

| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|-----------------------|--|-------------------------------|-----|--------|-----|------|
| R _{cpl} | coupling ratio | TX_gain1, and TX_gain2 | - | 25.5 | - | dB |
| $\Delta R_{cpl(f)}$ | variation of coupling ratio over frequency | measured in all TX_gain modes | - | +/-0.3 | - | dB |
| D | directivity | TX_gain1 | - | 17 | - | dB |
| | | TX_gain2 | - | 19 | - | dB |
| RL _{i(CPLR)} | coupler input return loss | looking into CPLR pin | - | 9.5 | - | dB |

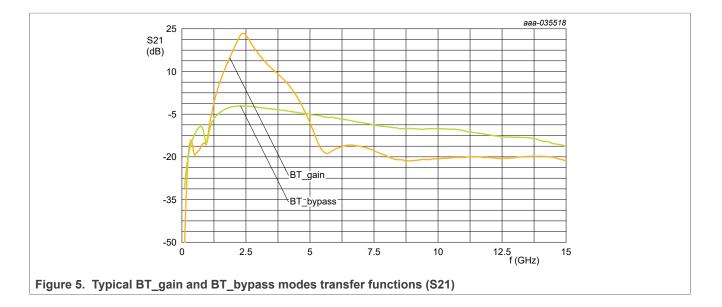
2.4 GHz Wi-Fi 6 Front-End Module

14 Graphics



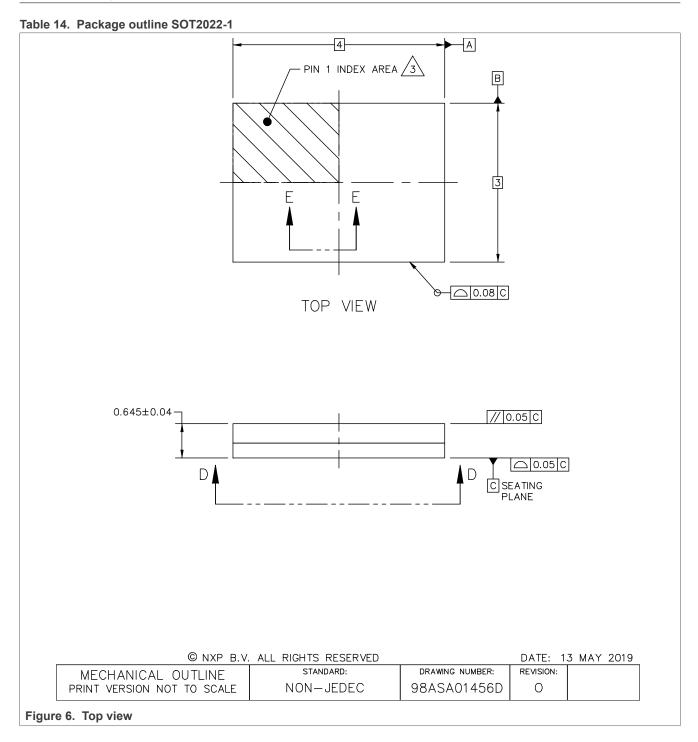


2.4 GHz Wi-Fi 6 Front-End Module



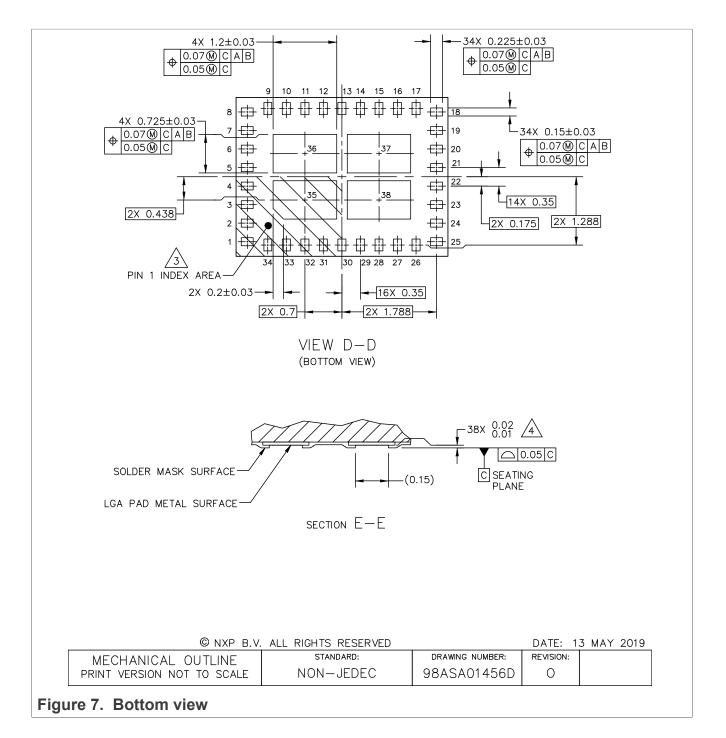
2.4 GHz Wi-Fi 6 Front-End Module

15 Package outline



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2.4 GHz Wi-Fi 6 Front-End Module

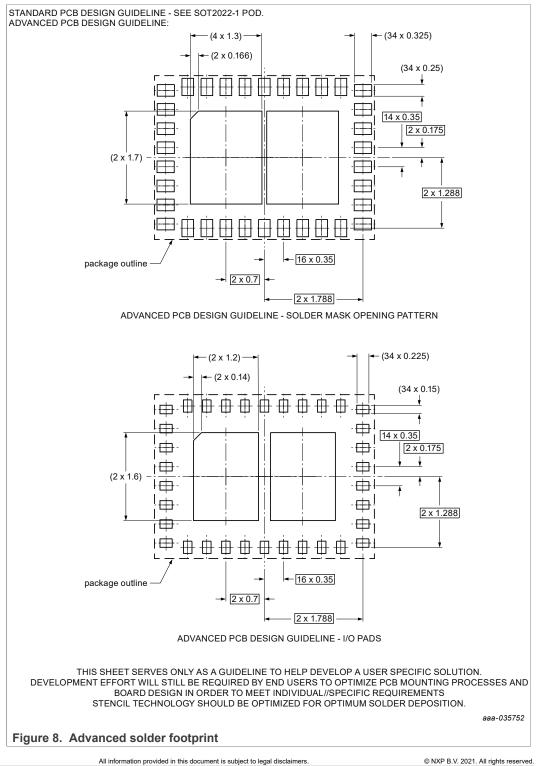


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15.1 Advanced solder footprint

NXP recommends by default to apply the soldering and footprint guidelines as are released in POD SOT2022-1.

Advanced PCB design guideline may be used when SOT2022-1 is applied with a non wet-able flank design. However, care should be taken in the design of the stencil to ensure optimal solder deposition.



16 Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices. Such precautions are described in the *ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A* or equivalent standards.

17 Abbreviations

| Acronym | Description |
|---------|---|
| ANT | antenna |
| BT | blue tooth |
| CDM | charge device model |
| CPLR | coupler |
| DC | direct current |
| ESD | electrostatic discharge |
| EVM | error vector magnitude |
| HBM | human body model |
| HFCPLGA | heat sink flip chip power land grid array |
| ISM | industrial scientific medical |
| ISL | isolation |
| LNA | low noise amplifier |
| LNAEN | low noise amplifier enable |
| LTE_LAA | LTE licensed assisted access |
| MCS | modulation code scheme |
| MIMO | multiple in multiple out |
| MSL | moisture sensitivity level |
| NF | noise figure |
| PA | power amplifier |
| PAEN | power amplifier enable |
| RF | radio frequency |
| RFFE | radio frequency front end |
| SEL | select |
| SPDT | single pole double throw |
| VSWR | voltage standing wave ratio |
| WLAN | wireless local area network |

18 Revision history

| Table 16. Revision hist | tory | | 1 | 1 | | | |
|-------------------------|---|---|---|---------------------------------|--|--|--|
| Document ID | Release date | Data sheet status | Change notice | Supersedes | | | |
| WLAN8101H v.6 | 20200811 | Product data sheet | - | WLAN8101H v.5 | | | |
| modification | changed status | from Company confident | ial to Public | | | | |
| WLAN8101H v.5 | 20200721 | Product data sheet | - | WLAN8101H v.4 | | | |
| modification | changed status | to Product data sheet | | | | | |
| WLAN8101H v.4 | 20200721 | Preliminary data sheet | - | WLAN8101H v.3 | | | |
| | adapted the coadapted the foradded BT to th | e for BT inband spurious e ndition for stability spuriou otnotes on RX IP3 _i , remov e Features and benefits bu tions on Switching time pe | is levels on XT, and ed 10 MHz, and ch ullet nr 4 | I BT anged -20 dBm to -3 dBm | | | |
| WLAN8101H v.3 | 20200330 | Preliminary data sheet | - | WLAN8101H v.2.1 | | | |
| modification | changed condition | tions of G _{flat} for ANT to RX | (from 80 MHz to 40 |) MHz | | | |
| WLAN8101H v.2.1 | 20200330 | Preliminary data sheet | - | WLAN8101H v.2 | | | |
| modification | Corrected typo | in Limiting values MSC0 | should be MCS0 | | | | |
| WLAN8101H v.2 | 20200316 | | - | WLAN8101H v.1 | | | |
| modification | | Changed name of CONTROL_4 to GND in the pinning diagram and pinning list and removed it from the Parallel interface control states table | | | | | |
| WLAN8101H v.1 | 20191219 | Preliminary data sheet | | | | | |

19 Legal information

19.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

Please consult the most recently issued document before initiating or completing a design. [1]

[2] [3] The term 'short data sheet' is explained in section "Definitions".

The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Product data sheet

2.4 GHz Wi-Fi 6 Front-End Module

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